

#### 3rd Generation 650 V, 30 A Silicon Carbide Schottky Diode

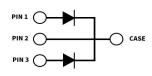
#### **Description**

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.









Package Types: TO-247-3 Marking: C3D30065

#### **Features**

- High-Frequency Operation
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Parallel Devices Without Thermal Runaway

#### **Applications**

- Boost Diodes in PFC or DC/DC Stages
- Free Wheeling Diodes in Inverter Stages
- Switch Mode Power Supplies
- Solar Inverters
- AC/DC Converters

# **Maximum Ratings** ( $T_c = 25^{\circ}$ C Unless Otherwise Specified)

\* Per Leg, \*\* Per Device

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	650				
Surge Peak Reverse Voltage	V <sub>RSM</sub>	650	V			
DC Blocking Voltage	V <sub>DC</sub>	650				
Continuous Forward Current (Per Leg/Per Device)	I <sub>F</sub>	39*/78**	A	T <sub>c</sub> = 25 °C		
		18*/36**		T <sub>c</sub> = 135 °C	Fig. 3	
		15*/30**		T <sub>c</sub> = 145 °C		
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	66*		$T_c = 25  ^{\circ}\text{C}, t_p = 10  \text{ms},  \text{Half Sine Wave}$		
		46*		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms},  \text{Half Sine Wave}$		
Non-Repetitive Forward Surge Current	I <sub>FSM</sub>	162**		$T_c = 25 ^{\circ}\text{C}$ , $t_p = 10 \text{ms}$ , Half Sine Wave		
		150**		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Wave}$	Fig. 8	
Non-Repetitive Peak Forward Surge Current	I <sub>F,Max</sub>	1400**		$T_c = 25 ^{\circ}\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$		
		1200**		$T_{c} = 110 {}^{\circ}\text{C}, t_{D} = 10 \mu\text{s}, \text{Pulse}$		
Power Dissipation	P <sub>tot</sub>	150*	W	T <sub>c</sub> = 25 °C		
		65*		T <sub>C</sub> = 110 °C	Fig. 4	
i²t value	ʃi²dt	131*	A <sup>2</sup> s	T <sub>c</sub> = 25C, tp=10ms		
		112.5*		T <sub>C</sub> = 110C, tp=10ms		
Diode dV/dt Ruggedness	dV/dt	200	V/ns	V <sub>R</sub> = 0-600V		

#### **Electrical Characteristics**

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
Forward Voltage	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	1.45	1.8	V	I <sub>F</sub> = 16 A, T <sub>j</sub> = 25 °C	Fig. 1
	V <sub>F</sub>	2.0	2.4		I <sub>F</sub> = 16 A, T <sub>j</sub> = 175 °C	
Reverse Current		18.5	95	μΑ	$V_R = 650 \text{ V}, T_j = 25 \text{ °C}$	Fig. 2
	I <sub>R</sub>	38.5	378		V <sub>R</sub> = 650 V, T <sub>j</sub> = 175 °C	
Total Capacitive Charge	Q <sub>c</sub>	44.5		nC	V <sub>R</sub> = 400 V, T <sub>j</sub> = 25 °C I <sub>F</sub> = 16A, di/dt = 500A/μs	Fig. 5
		877.5			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Total Capacitance	С	80		pF	$V_R = 200 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6
		64			$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Capacitance Stored Energy	E <sub>c</sub>	6.2		μJ	V <sub>R</sub> = 400 V	Fig. 7

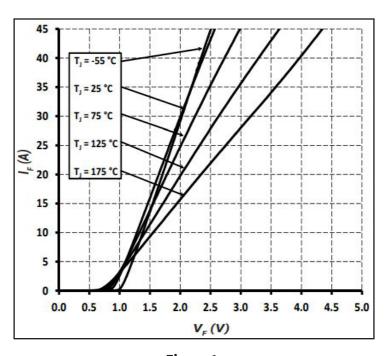
SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

#### **Thermal & Mechanical Characteristics**

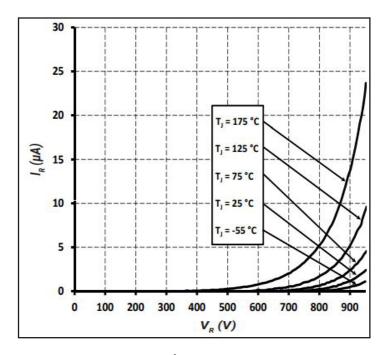
Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R <sub>0, JC (TYP)</sub>	1* 0.5**	°C/W	
Junction Temperature	T <sub>j</sub>	-55 to +175	0.0	
Case & Storage Temperature	T <sub>c</sub>	-55 to +175	°C	
		1	Nm	M3 Screw
TO-247 Mounting Torque	-	8.8	lbf-in	6-32 Screw

<sup>\*</sup> Per Leg, \*\* Per Device

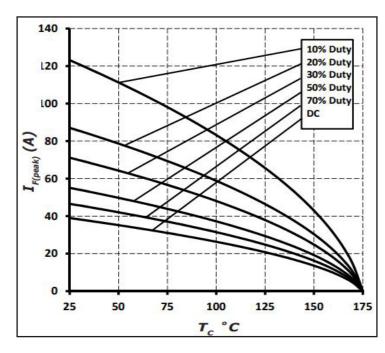
## **Typical Performance**



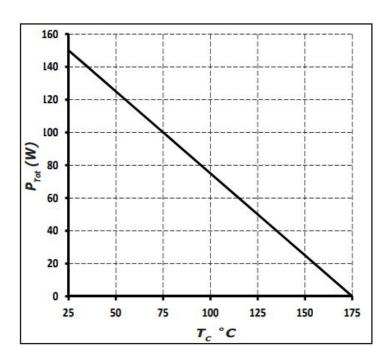
**Figure 1**Forward Characteristics



**Figure 2**Reverse Characteristics

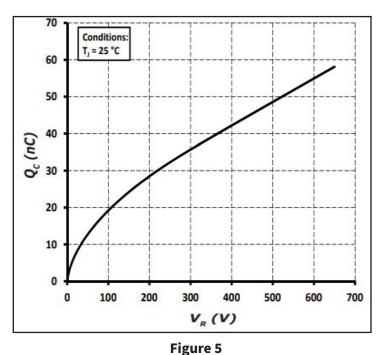


**Figure 3**Current Derating

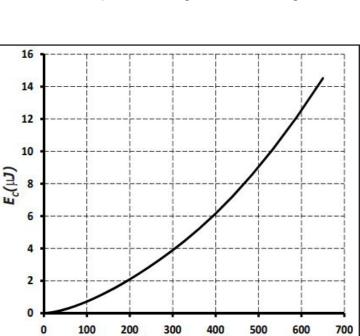


**Figure 4**Power Derating

#### **Typical Performance**

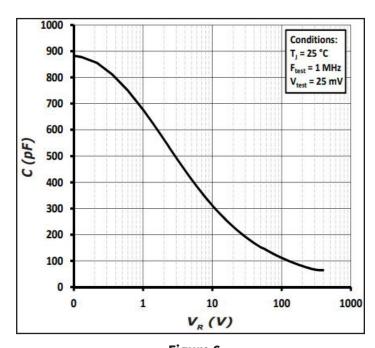


Total Capacitance Charge vs. Reverse Voltage

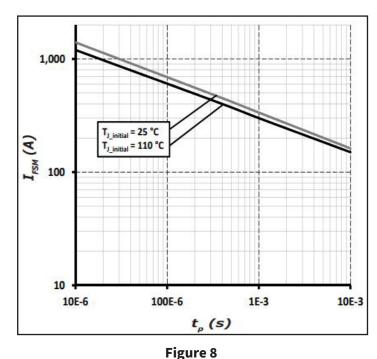


**Figure 7**Capacitance Stored Energy

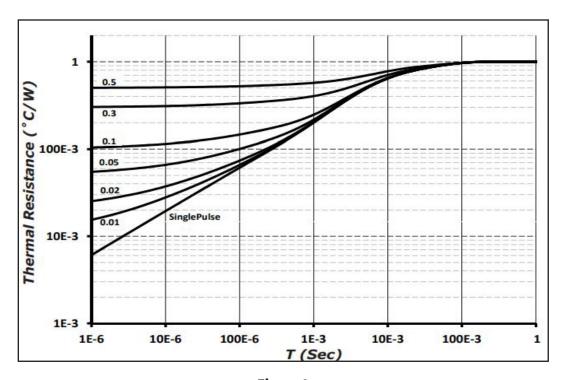
 $V_R(V)$ 



**Figure 6**Capacitance vs. Reverse Voltage



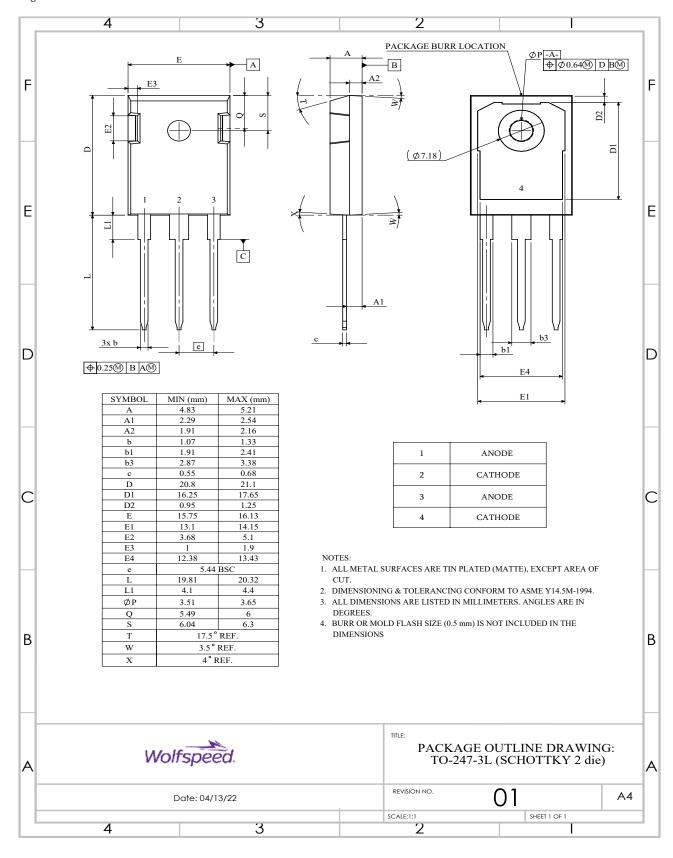
Non-Repetitive Peak Forward Surge Current vs. Pulse Duration



**Figure 9**Transient Thermal Impedance

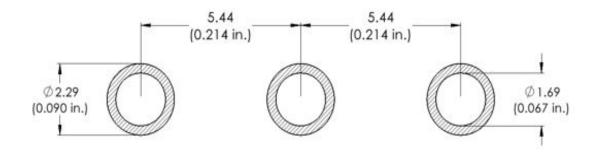
#### **Package Dimensions & Pin-Out**

Package: TO-247-3



#### **Recommended Solder Pad Layout**

Primary dimensions shown in mm.



#### **Diode Model**

$$\begin{array}{c|c} - & & \\ \hline V_T & & \\ \hline R_T \end{array}$$

$$Vf_T = V_T + If * R_T$$
  
 $V_T = 0.94 + (T_J * -1.0*10^{-3})$   
 $R_T = 0.027 + (T_J * 2.8*10^{-4})$ 

Note: T<sub>j</sub> = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

## **Product Ordering Information**

Order Number	Packing Type
C3D300065D	Tube

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

# **Revision History**

Document Version	Date of Release	Description of Changes
-	September- 2016	Initial Release
1	November-2023	Update Branding, POD, Package Image, Solder pad layout

#### Notes & Disclaimer

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